

COMPLIANT

N-Channel 20-V (D-S) 175 °C MOSFET

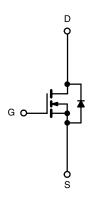
PRODUCT SUMMARY				
V _{(BR)DSS} (V)	(BR)DSS (V) r _{DS(on)} (Ω)			
20	0.0039 at V _{GS} = 10 V	60		
	0.0052 at V _{GS} = 4.5 V	60		

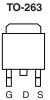
FEATURES

- TrenchFET[®] Power MOSFET
- 175 °C Junction Temperature
- 100 % R_g Tested
- 100 % UIS Tested

APPLICATIONS

• OR-ing





Top View

DRAIN connected to TAB

Ordering Information: SUM60N02-3m9P-E3 (Lead (Pb)-free)

N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS $T_A = 25 \degree C$, unless otherwise noted					
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	20	v	
Gate-Source Voltage		V _{GS}	± 20	- V	
Continuous Drain Current (T 175 %C)	T _C = 25 °C	1-	60 ^a		
Continuous Drain Current ($T_J = 175 \ ^{\circ}C$)	T _C = 100 °C	– I _D –	60 ^a	•	
Pulsed Drain Current		I _{DM}	120	A	
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	50		
Single Pulse Avalanche Energy		E _{AS}	125	mJ	
	T _C = 25 °C	P	120 ^c		
Maximum Power Dissipation ^b	T _A = 25 °C ^d	– P _D –	3.75	W	
Operating Junction and Storage Temperature Ra	nge	T _J , T _{stg}	- 55 to 175	°C	

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Limit	Unit		
Junction-to-Ambient (PCB Mount) ^d	R _{thJA}	40	°C/W		
Junction-to-Case	R _{thJC}	1.25			

Notes:

a. Package limited.

a. Factage innica.
b. Duty cycle ≤ 1 %.
c. See SOA curve for voltage derating.
d. When mounted on 1" square PCB (FR-4 material).

SUM60N02-3m9P

Vishay Siliconix



Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static			1				
Drain-Source Breakdown Voltage	V _{(BR)DSS}	$V_{DS} = 0 \text{ V}, \text{ I}_{D} = 250 \mu\text{A}$	20				
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	1.0		3	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
		$V_{DS} = 20 V, V_{GS} = 0 V$			1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 20 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 125 ^{\circ}\text{C}$			50	μA	
		$V_{DS} = 20 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 175 ^{\circ}\text{C}$			250		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, \text{ V}_{GS} = 10 \text{ V}$	100			Α	
		$V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$		0.0031	0.0039	Ω	
		V_{GS} = 10 V, I _D = 20 A, T _J = 125 °C			0.0059		
Drain-Source On-State Resistance ^a	r _{DS(on)}	V_{GS} = 10 V, I _D = 20 A, T _J = 175 °C			0.007		
		$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 20 \text{ A}$		0.0042	0.0052		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 10 V, I _D = 20 A		95		S	
Dynamic ^b			•	•	• •		
Input Capacitance	C _{iss}			5950		pF	
Output Capacitance	C _{oss}	V _{GS} = 0 V, V _{DS} = 10 V, f = 1 MHz		985			
Reverse Transfer Capacitance	C _{rss}			365			
Total Gate Charge ^b	Qg			33	50	nC	
Gate-Source Charge ^b	Q _{gs}	V_{DS} = 10 V, V_{GS} = 4.5 V, I_{D} = 50 A		18			
Gate-Drain Charge ^b	Q _{gd}			7			
Gate Resistance	R _g		0.75	1.5	2.3	Ω	
Turn-On Delay Time ^b	t _{d(on)}			15	25		
Rise Time ^b	t _r	V_{DD} = 10 V, R_L = 0.2 Ω		7	11	ns	
Turn-Off Delay Time ^b	t _{d(off)}	$\text{I}_\text{D} \cong$ 50 A, V_GEN = 10 V, R_g = 1.0 Ω		35	55		
Fall Time ^b	t _f			8	12		
Source-Drain Diode Ratings and Cha	aracteristics T	$T_{\rm C} = 25 \ ^{\circ}{\rm C}^{\rm C}$					
Continuous Current	ا _S				60	- A	
Pulsed Current	I _{SM}				100		
Forward Voltage ^a	V _{SD}	$I_{F} = 20 \text{ A}, V_{GS} = 0 \text{ V}$		0.85	1.5	V	
Reverse Recovery Time	t _{rr}			45	90	ns	
Peak Reverse Recovery Current	I _{RM}	$I_{F} = 20 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}$		1.7	3.4	Α	
Reverse Recovery Charge	Q _{rr}	\neg		0.039	0.155	μC	

Notes:

a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %

b. Independent of operating temperature.

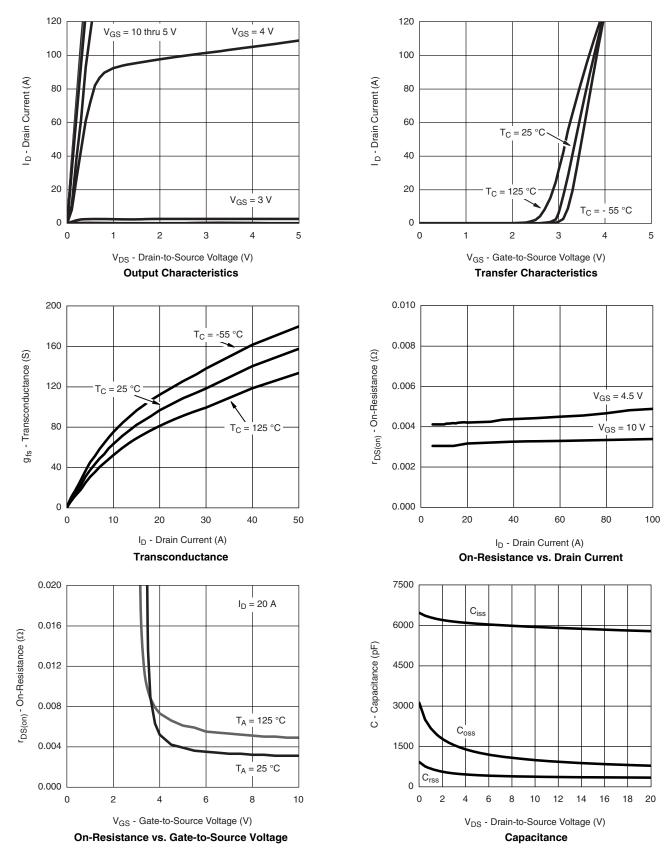
c. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



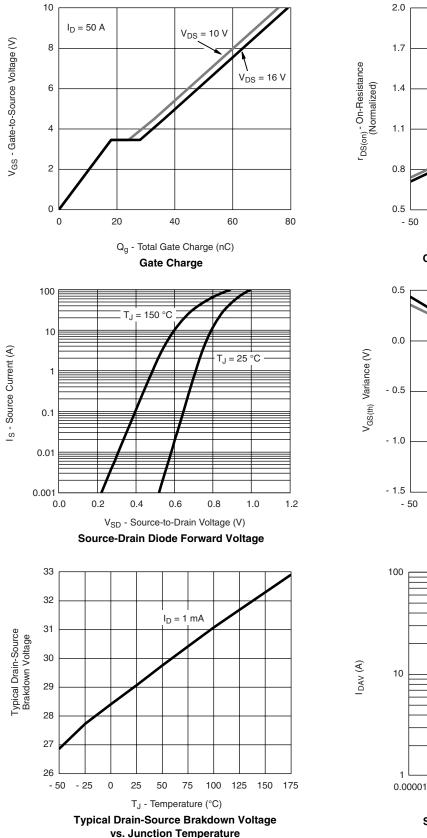
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

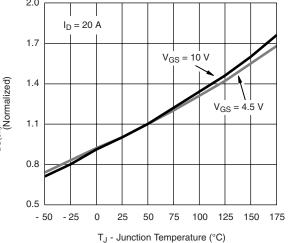
VISHAY



Document Number: 69820 S-80183-Rev. A, 04-Feb-08

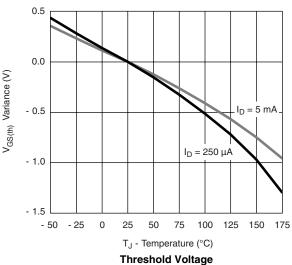
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

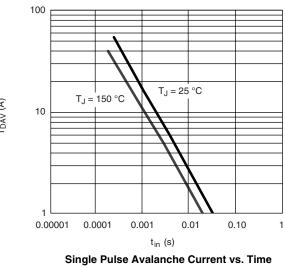


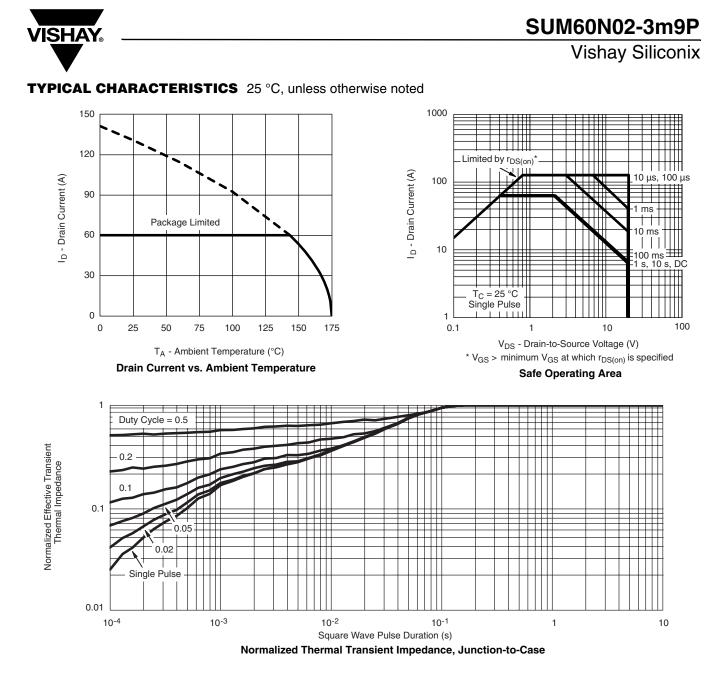


VISHAY

On-Resistance vs. Junction Temperature







Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?69820.



TO-263 (D²PAK): 3-LEAD









DETAIL A (ROTATED 90°)



		INCHES		MILLIN	IETERS	
DIM.		MIN.	MAX.	MIN.	MAX.	
А		0.160	0.190	4.064	4.826	
	b	0.020	0.039	0.508	0.990	
	b1	0.020	0.035	0.508	0.889	
	b2	0.045	0.055	1.143	1.397	
с*	Thin lead	0.013	0.018	0.330	0.457	
C	Thick lead	0.023	0.028	0.584	0.711	
c1	Thin lead	0.013	0.017	0.330	0.431	
CI	Thick lead	0.023	0.027	0.584	0.685	
	c2	0.045	0.055	1.143	1.397	
	D	0.340	0.380	8.636	9.652	
	D1	0.220	0.240	5.588	6.096	
D2		0.038	0.042	0.965	1.067	
D3		0.045	0.055	1.143	1.397	
D4		0.044	0.052	1.118	1.321	
	E	0.380	0.410	9.652	10.414	
	E1	0.245	-	6.223	-	
	E2	0.355	0.375	9.017	9.525	
	E3	0.072	0.078	1.829	1.981	
	е	0.100	0.100 BSC 2.54 BS		BSC	
	К	0.045	0.055	1.143	1.397	
	L	0.575	0.625	14.605	15.875	
	L1	0.090	0.110	2.286	2.794	
	L2	0.040	0.055	1.016	1.397	
	L3	0.050	0.070	1.270	1.778	
	L4	0.010 BSC		0.254 BSC		
	М	M - 0.002 - 0.050		0.050		
ECN: T13-0707-Rev. K, 30-Sep-13 DWG: 5843						

Notes

- 1. Plane B includes maximum features of heat sink tab and plastic. 2. No more than 25 % of L1 can fall above seating plane by
- max. 8 mils.3. Pin-to-pin coplanarity max. 4 mils.
- 4. *: Thin lead is for SUB, SYB.
 - Thick lead is for SUM, SYM, SQM.
- 5. Use inches as the primary measurement.

This feature is for thick lead.

Revison: 30-Sep-13



RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

Return to Index



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Vishay: SUM60N02-3M9P-E3